

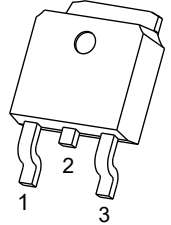
**TO-252-2L Plastic-Encapsulate MOSFETS****CJU15N10 N-Channel Power MOSFET**

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
100V	70mΩ@10V	15A

DESCRIPTION

The CJU15N10 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications

TO-252-2L

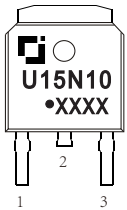
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1. GATE
 2. DRAIN
 3. SOURCE

FEATURE

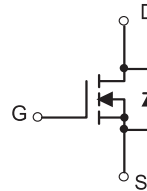
- Excellent package for good heat dissipation
- Ultra low gate charge
- Low reverse transfer capacitance
- Fast switching capability
- Avalanche energy specified

APPLICATION

- Power switching application

MARKING

U15N10 = Device code.
Solid dot = Green molding compound device,
if none, the normal device.
XXXX = Code.

EQUIVALENT CIRCUIT**MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D ①	15	A
Pulsed Drain Current	I_{DM} ②	60	A
Single Pulsed Avalanche Energy	E_{AS} ③	49	mJ
Power Dissipation	P_D ①	45	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$ ⑥	100	°C/W
Thermal Resistance from Junction to Case	$R_{\theta JC}$ ①	2.78	°C/W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	°C

MOSFET ELECTRICAL CHARACTERISTICS

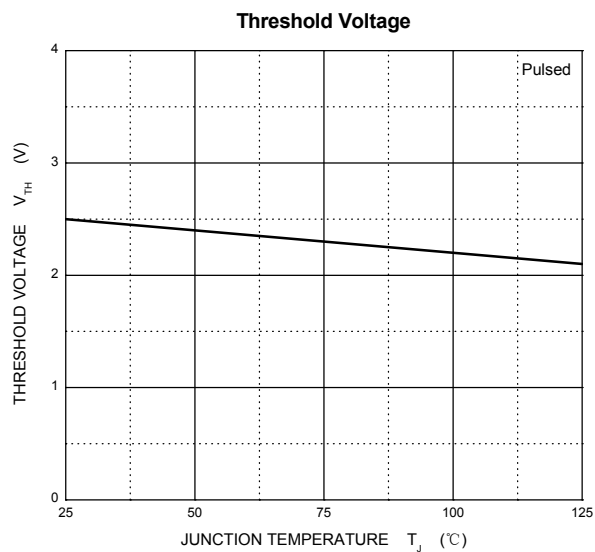
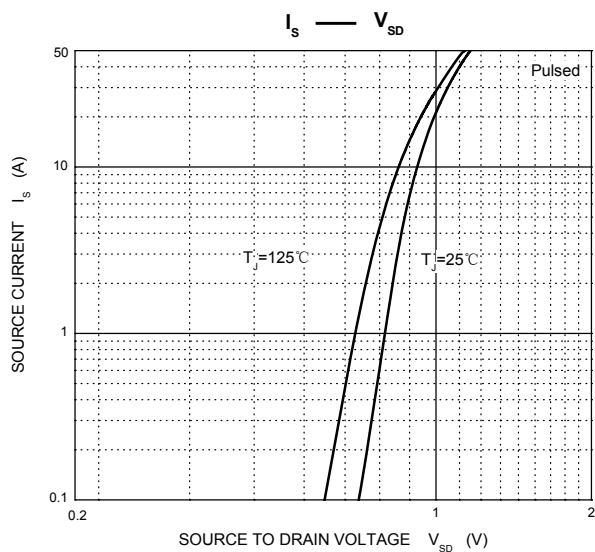
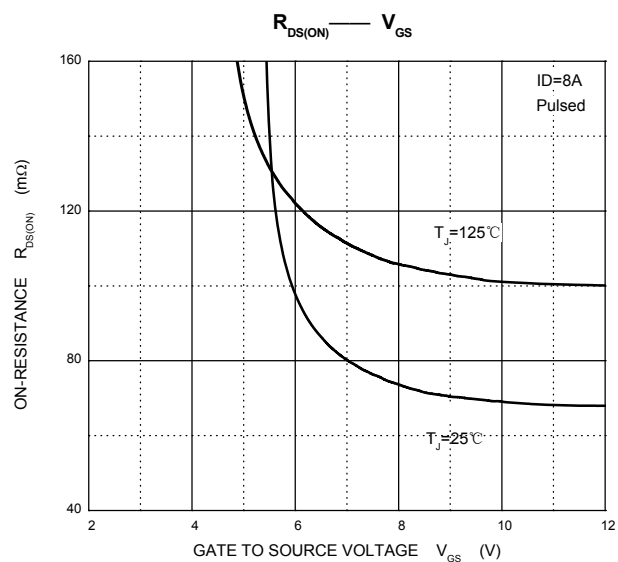
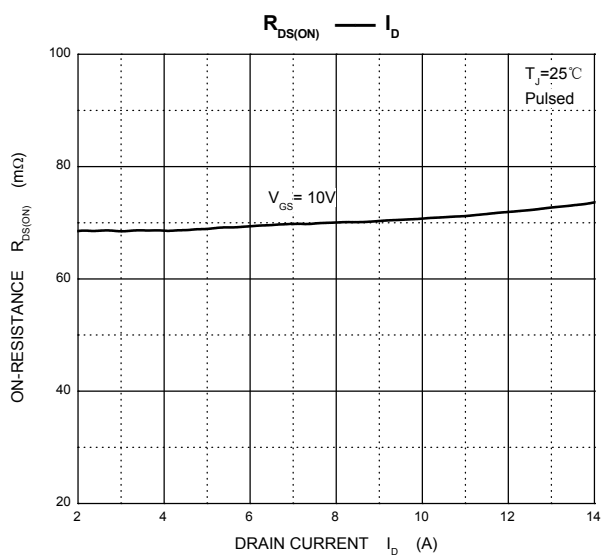
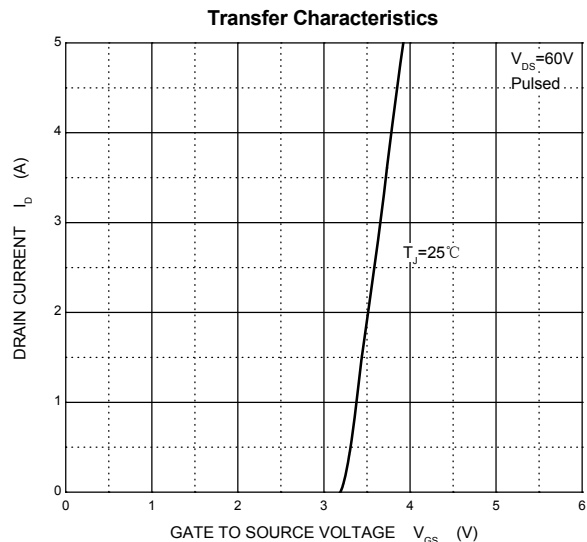
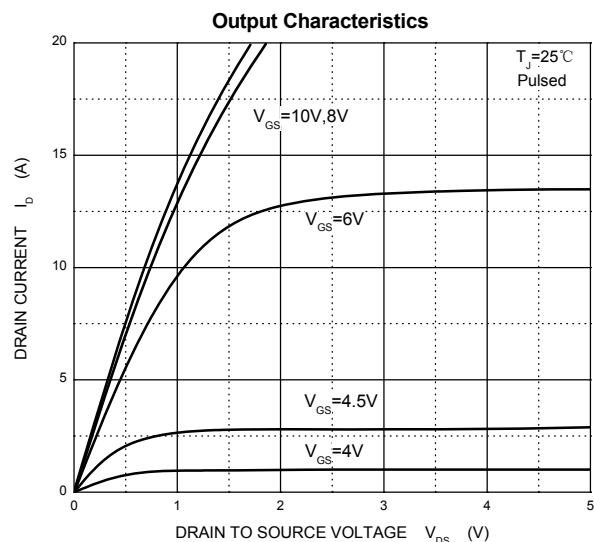
$T_a=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition		Min	Typ	Max	Unit
Off characteristics							
Drain-source breakdown voltage	V _{(BR) DSS}	V _{GS} = 0V, I _D =250μA		100			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =80V, V _{GS} =0V	T _J =25 ℃			1.0	μA
			T _J =125 ℃			100	
Gate-body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V				±100	nA
On characteristics ④							
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA		1.0	2.5	3.0	V
Static drain-source on-sate resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A			70	100	mΩ
Dynamic characteristics ④ ⑤							
Input capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V, f = 100KHz			773	1500	pF
Output capacitance	C _{oss}				46	92	
Reverse transfer capacitance	C _{rss}				43	90	
Gate resistance	R _g	f =1MHz			1.5		Ω
Switching characteristics ④ ⑤							
Total gate charge	Q _g	V _{GS} =10V, V _{DS} =50V, I _D =10A			18	36	nC
Gate-source charge	Q _{gs}				2.8	5.6	
Gate-drain charge	Q _{gd}				7.4	14.8	
Turn-on delay time	t _{d(on)}	V _{DD} =25V,R _L =5Ω, V _{GS} =10V,R _G =1.0Ω			15		ns
Turn-on rise time	t _r				33		
Turn-off delay time	t _{d(off)}				41		
Turn-off fall time	t _f				6		
Drain-Source Diode Characteristics							
Drain-source diode forward voltage	V _{SD} ④	V _{GS} =0V, I _S =8A				1.2	V
Continuous drain-source diode forward current	I _S ①					15	A
Pulsed drain-source diode forward current	I _{SM} ②					60	A

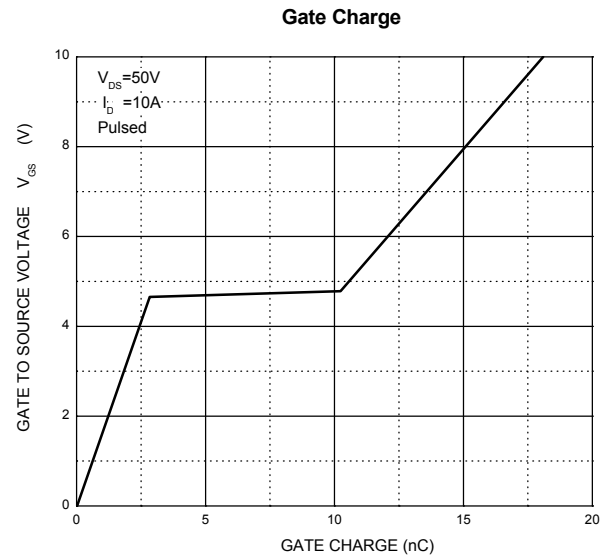
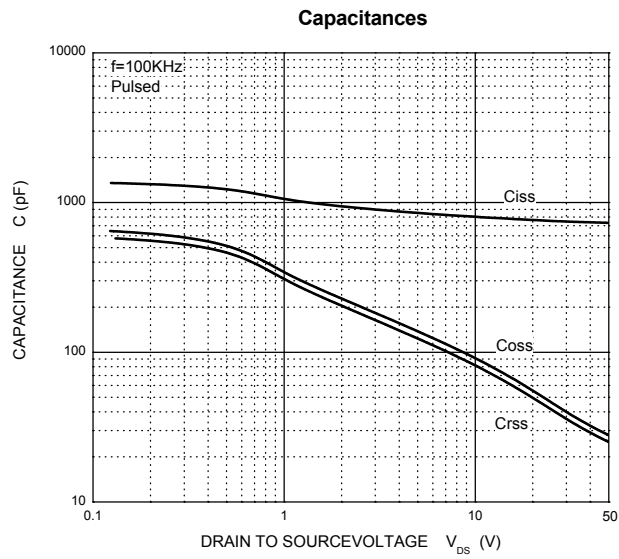
Notes:

1. $T_C = 25^{\circ}\text{C}$ Limited only by maximum temperature allowed.
2. $P_W \leq 10\mu s$, Duty cycle $\leq 1\%$.
3. EAS condition: $V_{DD} = 25V, V_{GS} = 10V, L = 0.5mH, R_g = 25\Omega$ Starting $T_J = 25^{\circ}\text{C}$.
4. Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
5. Guaranteed by design, not subject to production.
6. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with $T_a = 25^{\circ}\text{C}$.

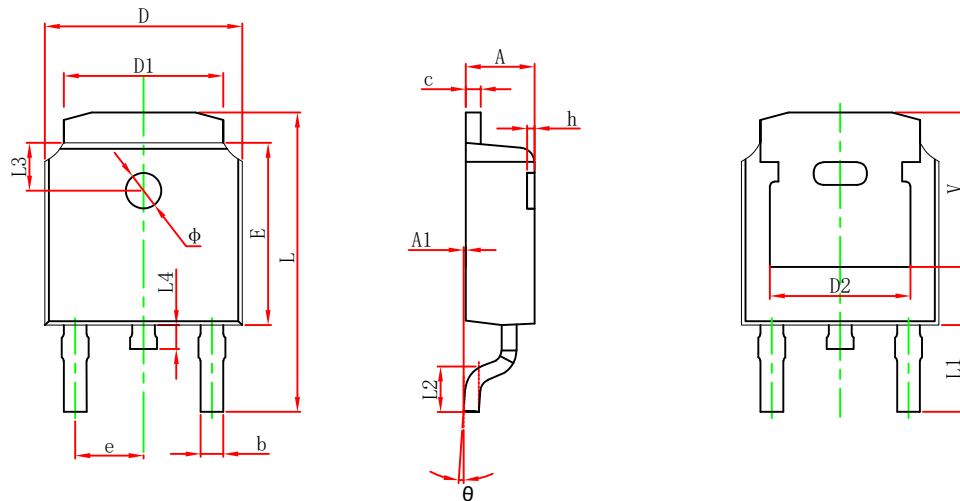
Typical Characteristics



Typical Characteristics

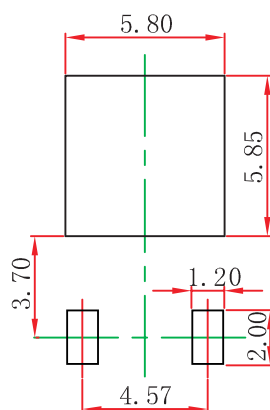


TO-252-2L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.382	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	

TO-252-2L Suggested Pad Layout



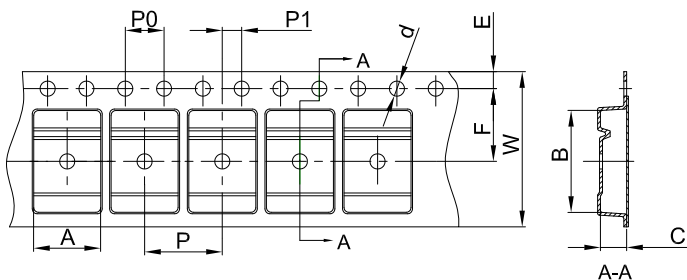
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

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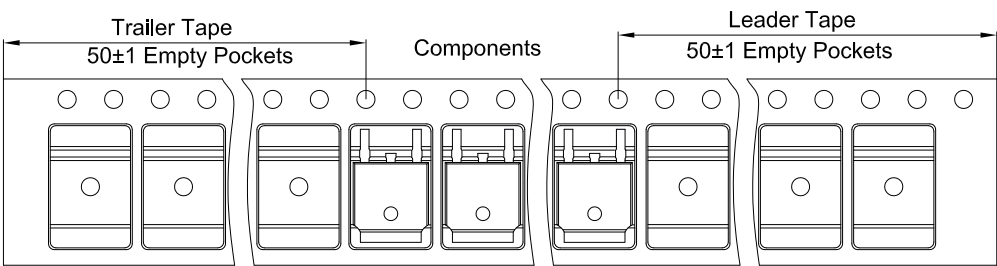
TO-252 Embossed Carrier Tape



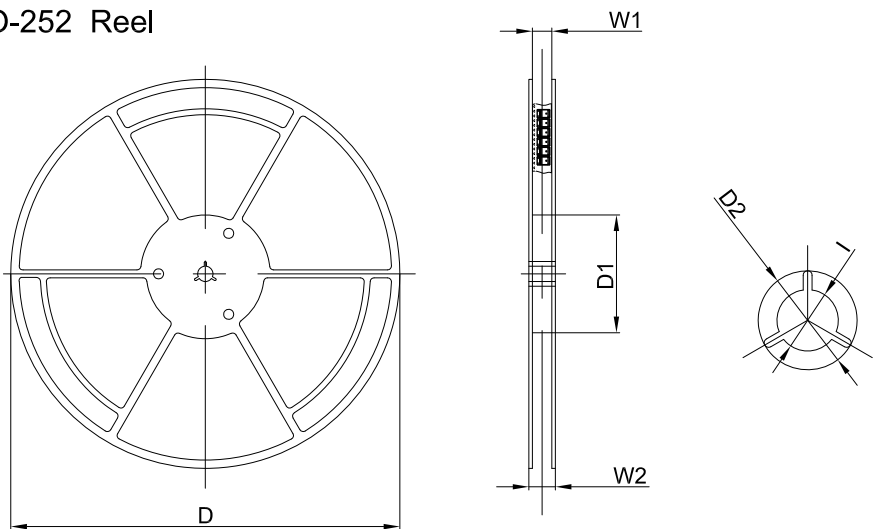
Packaging Description:
TO-252 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 25,00 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
TO-252	6.90	10.50	2.70	Ø1.55	1.75	7.50	4.00	8.00	2.00	16.00

TO-252 Tape Leader and Trailer



TO-252 Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	W1	W2	I
13"Dia	330.00	100.00	Ø21.00	16.40	21.00	Ø13.00

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
2,500 pcs	13inch	2,500 pcs	340×336×29	25,000 pcs	353×346×365	

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